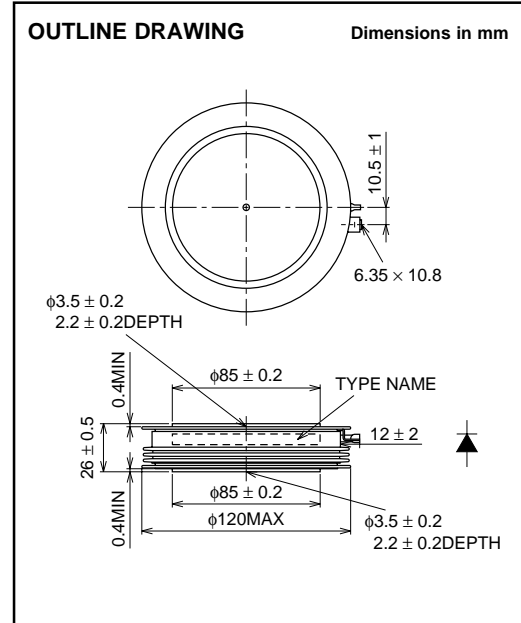
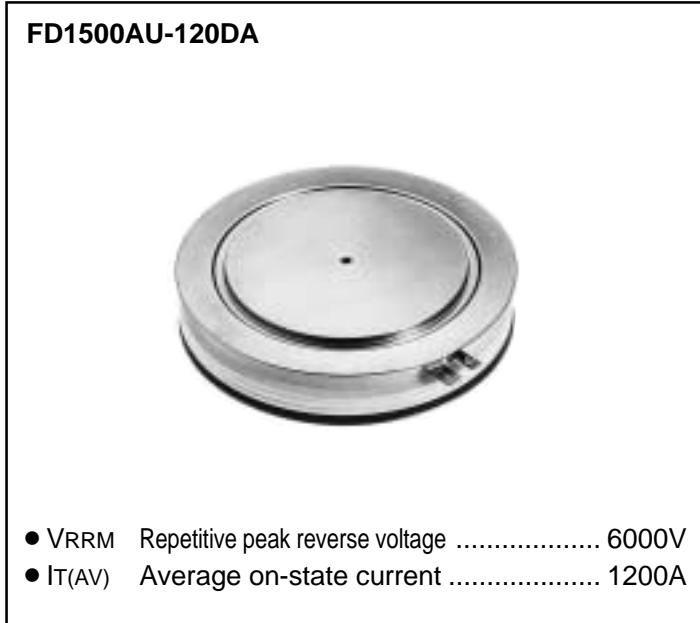


PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

MITSUBISHI SOFT RECOVERY DIODE FD1500AU-120DA

**HIGH POWER, HIGH FREQUENCY
 PRESS PACK TYPE**



APPLICATION

- High-power inverters
- Fly-hwheel diode for GCT Thyristor
- Power supplies as high frequency rectifiers

MAXIMUM RATINGS

| Symbol | Parameter | Conditions | Voltage class | Unit |
|---------|-------------------------------------|---------------------------|---------------|------|
| VRRM | Repetitive peak reverse voltage | — | 6000 | V |
| VRSM | Non-repetitive peak reverse voltage | — | 6000 | V |
| VR(DC) | DC reverse voltage | — | 4800 | V |
| V(LTDS) | Long term DC stability voltage | $\lambda = 100\text{Fit}$ | 3200 | V |

| Symbol | Parameter | Conditions | Ratings | Unit |
|-----------|---|--|-------------------|------------------------|
| IF(RMS) | RMS forward current | Applied for all condition angles | 1900 | A |
| IF(AV) | Average forward current | $f = 60\text{Hz}$, sinewave $\theta = 180^\circ$, $T_r = 74^\circ\text{C}$ | 1200 | A |
| IFSM | Surge forward current | One half cycle at 60Hz, $T_j = 125^\circ\text{C}$ start | 26 | kA |
| I^2t | Current-squared, time integration | | 2.8×10^6 | A^2s |
| di/dt | Critical rate of rise of reverse recovery current | $I_{FM} = 1500\text{A}$, $V_R = 3000\text{V}$, $T_j = 25/125^\circ\text{C}$ $C_C = 6\mu\text{F}$, $L_C = 0.3\mu\text{H}$ (See Fig. 1, 2) | 1000 | $\text{A}/\mu\text{s}$ |
| T_j | Operation junction temperature | | -40 ~ 125 | $^\circ\text{C}$ |
| T_{stg} | Storage temperature | | -40 ~ 150 | $^\circ\text{C}$ |
| — | Mounting force required | (Recommended value 47kN) | 39 ~ 55 | kN |
| — | Weight | Typical value 1450g | — | g |

ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test conditions | Limits | | | Unit |
|---------------|---------------------------------|---|--------|------|--------|---------------|
| | | | Min. | Typ. | Max. | |
| VFM | Forward voltage | $I_{FM} = 3400\text{A}$, $T_j = 125^\circ\text{C}$ | — | — | 5 | V |
| IRRM | Repetitive peak reverse current | $V_{RM} = 6000\text{V}$, $T_j = 125^\circ\text{C}$ | — | — | 150 | mA |
| QRR | Reverse recovery charge | $I_{FM} = 1500\text{A}$, $di/dt = 1000\text{A}/\mu\text{s}$, $V_R = 3000\text{V}$, $T_j = 125^\circ\text{C}$ | — | — | 5400 | μC |
| Erec | Reverse recovery energy | $C_C = 6\mu\text{F}$, $L_C = 0.3\mu\text{H}$ (See Fig. 1, 2) | — | — | 9.4 | J/P |
| $R_{th(j-f)}$ | Thermal resistance | Junction to Fin | — | — | 0.0071 | K/W |

PRELIMINARY
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FD1500AU-120DA

**HIGH POWER, HIGH FREQUENCY
 PRESS PACK TYPE**

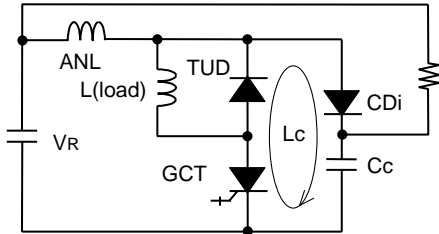


Fig. 1 Reverse recovery test circuit

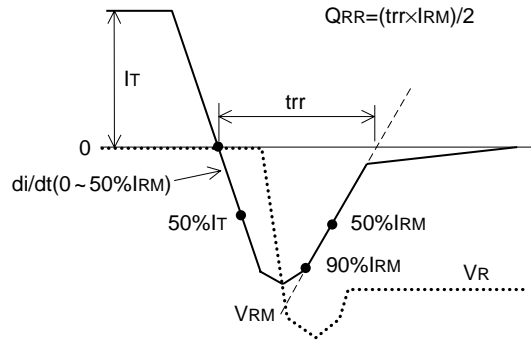


Fig. 2 Reverse recovery waveform

PERFORMANCE CURVES

